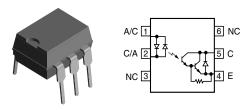
Vishay Semiconductors



Optocoupler, Photodarlington Output, AC Input, Internal RBE



i17904

DESCRIPTION

The IL766B is a bidirectional input, optically coupled isolator consisting of two gallium arsenide infrared emitters and a silicon photodarlington sensor.

FEATURES

- Internal RBE for better stability
- BV_{CEO} < 60 V
- Isolation test voltage, 5300 V_{RMS}
- · AC or polarity insensitive inputs
- · No base connection
- High insulation resistance, $10^{11} \Omega$ typical
- · Standard plastic DIP package
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



- UL1577, File No. E52744 system code H or J, double protection
- BSI IEC 60950 IEC 60065

ORDER INFORMATION				
PART	REMARKS			
IL766B-1	CTR > 400 %, DIP-6			
IL766B-2	CTR > 900 %, DIP-6			
IL766B-2X006	CTR > 900 %, DIP-6 400 mil (option 6)			

Note

For additional information on the available options refer to option information.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT		·					
Forward continuous current		I _F	60	mA			
Power dissipation		P _{diss}	200	mW			
Derate linearly from 55 °C			2.6	mW/°C			
OUTPUT		·					
Collector emitter breakdown voltage		BV _{CEO}	60	V			
Collector base breakdown voltage		BV _{CBO}	70	V			
Power dissipation		P _{diss}	200	mW			
Derate linearly from 25 °C			2.6	mW/°C			

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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
COUPLER	•						
UL Isolation test voltage		V _{ISO}	5300	V_{RMS}			
Total power dissipation	t = 1.0 s	P _{tot}	250	mW			
Derate linearly from 25 °C			3.3	mW/°C			
Creepage			≥ 7	min			
Clearance			≥ 7	min			
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	10 ¹²	Ω			
isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹	Ω			
Storage temperature		T _{stg}	- 55 to + 150	°C			
Operating temperature		T _{amb}	- 55 to + 150	°C			
Lead soldering time at 260 °C			10	s			

Note

 T_{amb} = 25 °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTCS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = \pm 10 \text{ mA}$		V _F		1.25	1.5	V
OUTPUT							
Collector emitter breakdown voltage	$I_C = 10 \text{ mA}, I_F = 0 \text{ A}$		BV _{CEO}	60			V
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, I_F = 0 \text{ A}$		I _{CEO}		1.0	100	nA
COUPLER							
Collector emitter, saturation voltage	$I_C = \pm 1.0 \text{ mA}, I_F = \pm 10 \text{ mA}$		V _{CEsat}			1.0	V

Note

 T_{amb} = 25 °C, unless otherwise specified.

Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

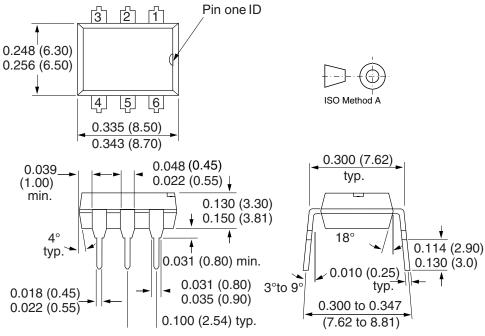
CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Saturation voltage, collector emitter	$I_C = \pm 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	IL766B-1	CTR	400			%
	$I_C = \pm 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	IL766B-2	CTR	900			%

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-off time	V_{CC} = 5.0 V, I_F = \pm 2.0 mA, R_L = 100 Ω	t _{off}		200		μs

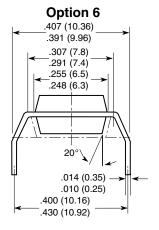


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PACKAGE DIMENSIONS in inches (millimeters)



i178004



18446

Vishay Semiconductors Optocoupler, Photodarlington Output, AC Input, Internal R_{BE}



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Vishay

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